

Title:	Performance Report SiT8008B, 33MHz			
Type:	Performance report Rev: 1.0			
Orig:		Date:	Mar 31, 2014	

This report contains sample performance data for SiT8008B-33MHz.

Conditions:

- Frequency 33 MHz
- Vdd 1.8V, 2.5V, 2.8V, 3.0V, 3.3V
- Temperature 25°C
- Termination:
 - No load for IDD
 - \circ 50 Ω to GND for phase noise
 - o 15pF for other tests

Equipment:

- Agilent DSA90604 oscilloscope (6GHz, 20Gsps)
 - o Period jitter, waveform, rise/fall time, duty cycle, amplitude
- Agilent E5052B Signal Source Analyzer
 - o Phase noise, integrated phase jitter
- Power supply current
 - o Agilent 34401A DMM

Data:

- Random Phase jitter, Period Jitter, Duty cycle, Rise/Fall time, Amplitude, Idd
- Output waveforms
- Frequency stability versus temperature

Table 1. Performance data

Parameter	Units	Voltage				
raiametei	Office	1.8 V	2.5 V	2.8 V	3.0 V	3.3 V
Random Phase jitter (900kHz - 5MHz)	ps, rms	0.45	0.47	0.48	0.48	0.48
Random Phase jitter (12kHz - 5MHz)	ps, rms	1.19	1.19	1.19	1.20	1.19
Random Phase jitter (900kHz - 20MHz)*	ps, rms	0.70	0.74	0.74	0.75	0.75
Random Phase jitter (12kHz - 20MHz)*	ps, rms	1.31	1.33	1.32	1.33	1.32
Period jitter	ps, rms	1.84	1.71	1.68	1.67	1.64
Period jitter (10,000 cycles)	ps, pk-pk	13.9	12.5	12.3	12.1	11.8
Duty cycle	%	49.9	49.8	50.1	50.3	50.5
Rise time (20% - 80%)	ns	1.24	1.03	0.94	1.00	0.94
Fall time (80% - 20%)	ns	1.24	0.98	0.90	0.97	0.92
Amplitude	V	1.76	2.46	2.76	3.00	3.29
Current consumption (no load, output enabled)	mA	3.73	3.89	3.97	4.01	4.09
Current consumption (no load, output disabled)	mA	3.43	3.49	3.55	3.59	3.66

^{*}Calculated by extending the noise floor of the phase noise from 5 MHz to 20 MHz

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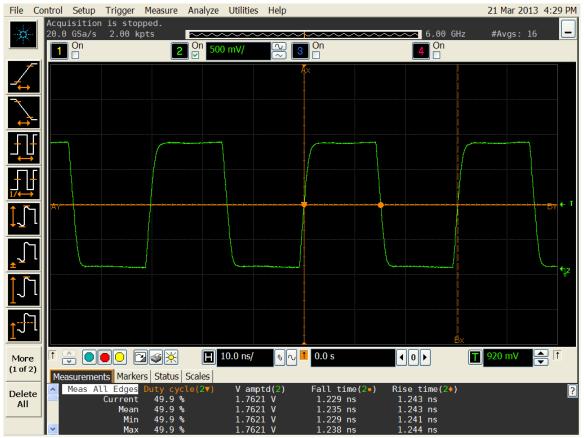


Figure 1. Duty cycle, Rise/Fall time and Amplitude 1.8V



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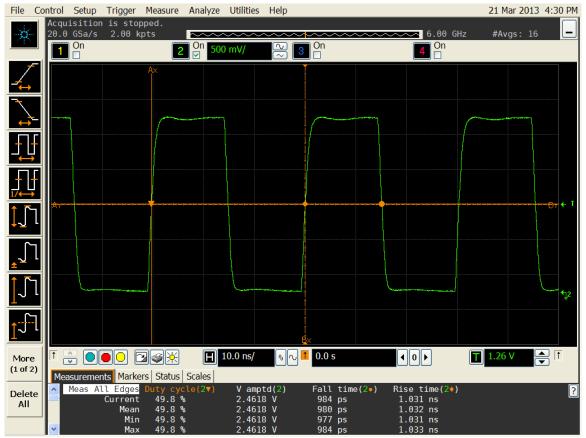


Figure 2. Duty cycle, Rise/Fall time and Amplitude 2.5V



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Figure 3. Duty cycle, Rise/Fall time and Amplitude 2.8V



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Figure 4. Duty cycle, Rise/Fall time and Amplitude 3.0V



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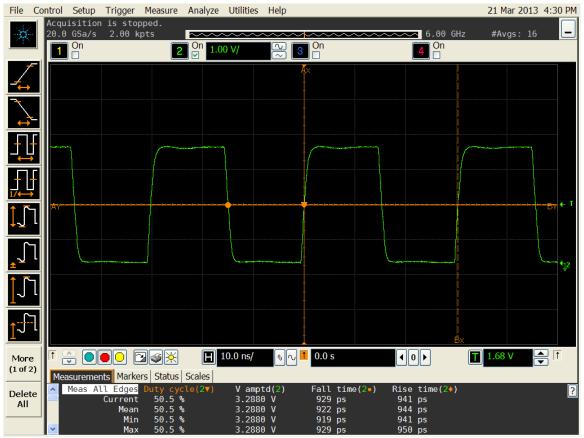


Figure 5. Duty cycle, Rise/Fall time and Amplitude 3.3V



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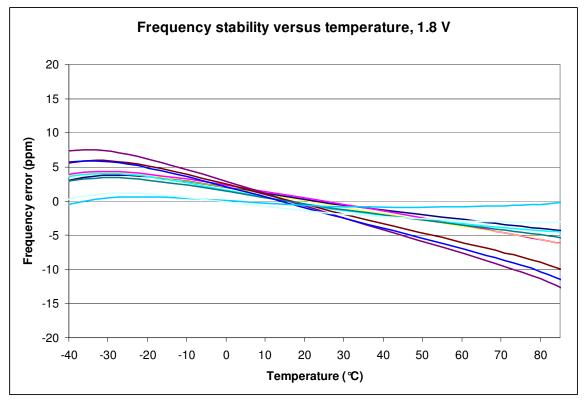


Figure 6. Frequency stability* versus temperature, 1.8 V

^{*}Please note that frequency stability in SiTime devices is not depended on output frequency.



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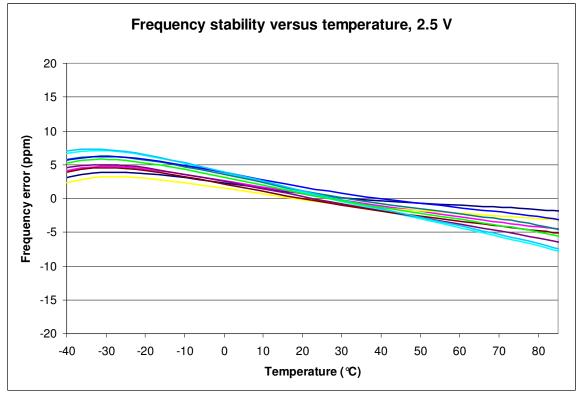


Figure 7. Frequency stability versus temperature, 2.5 V



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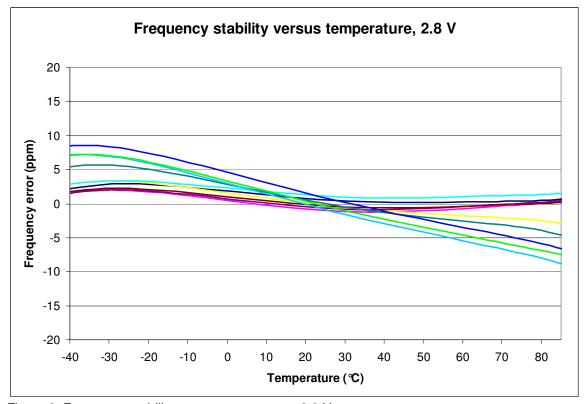


Figure 8. Frequency stability versus temperature, 2.8 V



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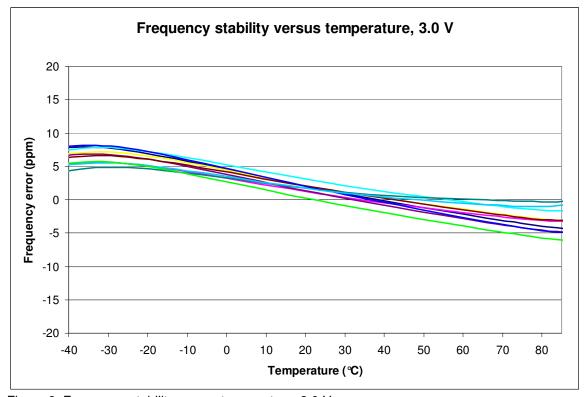


Figure 9. Frequency stability versus temperature, 3.0 V



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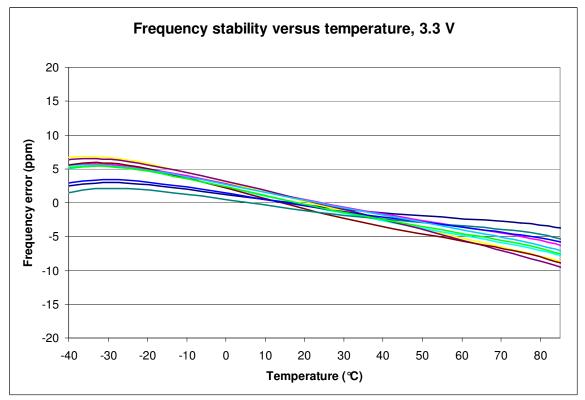


Figure 10. Frequency stability versus temperature, 3.3 V